

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	436	base near3 ((single adj2 silicon) or (silicon-germanium) or (germanium-silicon) or si-ge or ge-si)	USPAT; US-PG PUB	2003/08/28 14:03
2	BRS	L2	1852	emitter near3 (poly or polysilicon or polycrystalline)	USPAT; US-PG PUB	2003/08/28 14:04
3	BRS	L3	10	(base adj2 (contact or electrode)) near3 ((polysilicon or polycrystalline) near3 ((silicon-germanium) or (germanium-silicon) or si-ge or ge-si))	USPAT; US-PG PUB	2003/08/28 14:04
4	BRS	L4	8	1 and 2 and 3	USPAT; US-PG PUB	2003/08/28 14:07
5	BRS	L5	275	base near3 ((single adj2 silicon) or (silicon-germanium) or (germanium-silicon) or si-ge or ge-si)	EPO; JPO; DERWE NT; IBM_TD B	2003/08/28 14:03
6	BRS	L6	1163	emitter near3 (poly or polysilicon or polycrystalline)	EPO; JPO; DERWE NT; IBM_TD B	2003/08/28 14:04
7	BRS	L7	2	(base adj2 (contact or electrode)) near3 ((polysilicon or polycrystalline) near3 ((silicon-germanium) or (germanium-silicon) or si-ge or ge-si))	EPO; JPO; DERWE NT; IBM_TD B	2003/08/28 14:04
8	BRS	L8	1	5 and 6 and 7	EPO; JPO; DERWE NT; IBM_TD B	2003/08/28 14:06
9	IS&R	L9	1	("6365479").PN.	USPAT; US-PG PUB	2003/08/28 14:06
10	BRS	L10	163	1 and 2	USPAT; US-PG PUB	2003/08/28 14:07
11	BRS	L11	112	10 and ((base) adj2 (contact or electrode))	USPAT; US-PG PUB	2003/08/28 14:08
12	BRS	L12	37	11 and hbt	USPAT; US-PG PUB	2003/08/28 14:08